

Dual Schmitt-Trigger Buffer

Description

This dual buffer is designed for 1.65-V to 5.5-V VCC operation. The CMOS device provides high output drive while maintaining low static power consumption.

The FLG74LVC2G34 device performs the Boolean function $Y = A$. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

The FLG74LVC2G34 is available in a variety of packages, including SOT-23-6, SC70-6.

Features

- Supports 5-V V_{CC} Operation
- Max Tpd of 4.1 ns at 3.3 V
- Low Power Consumption, 10- μ A Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- Typical V_{OLP} (Output Ground Bounce) <0.8V at V_{CC} = 3.3V, TA = 25°C
- Typical V_{OHV} (Output VOH Undershoot) > 2V at V_{CC} = 3.3V, TA = 25°C
- I_{OFF} Supports Live Insertion, Partial-Power-Down-Mode and Back-Drive Protection

- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 1000-V Charged-Device Model (C101)

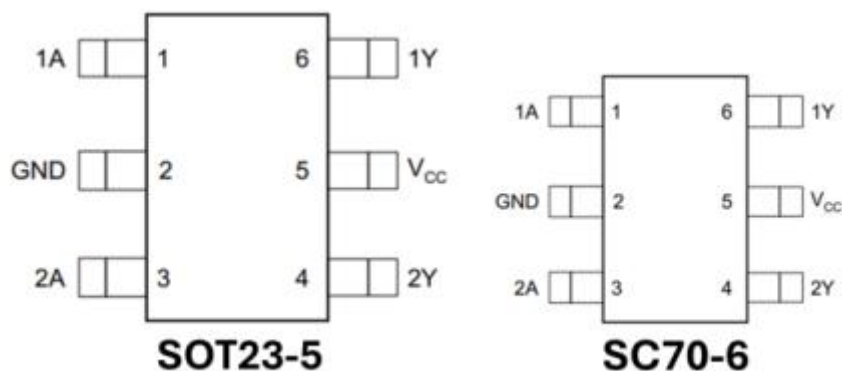
Applications

- IP Phones: Wired and Wireless
- Optical Modules
- Optical Networking: EPON and Video Over Fiber
- Point-to-Point Microwave Backhaul
- Power: Telecom DC/DC Module: Analog and Digital
- Private Branch Exchanges (PBX)
- TETRA Base Exchanges
- Telecom Base Band Units
- Tablet: Enterprise
- Telecom Shelters: Power Distribution Units (PDU), Power Monitoring Units (PMU), Wireless Battery Monitoring, Remote Electrical Tilt Units (RET), Remote Radio Units (RRU), Tower Mounted 1 Amplifiers (TMA)
- Vector Signal Analyzers and Generators

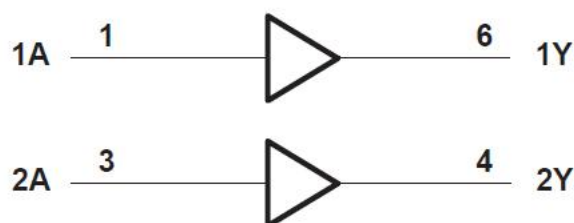
Order information

Mode	Package	Ordering Number	Packing Option
FLG74LVC2G34	SOT23-6	FLG74LVC2G34YSOT236G/TR	Tape and Reel,3000
	SC70-6	FLG74LVC2G34YSC706G/TR	Tape and Reel,3000

Pin Configuration



Simplified Schematic



Pin Assignment

Pin Name	Pin No.	Pin Function
GND	2	Ground
1A	1	Input 1
2A	3	Input 2
1Y	6	Open-drain output 1
2Y	4	Open-drain output 2
VCC	5	Power pin

Absolute Maximum Ratings (Note1)

- V_{CC} ----- -0.5V to +6.5V
- V_I ----- -0.5V to +6.5V
- V_O (Voltage range applied to any output in the high-impedance or power-off state) ----- -0.5V to +6.5V
- V_O (Voltage range applied to any output in the high or slow state) ----- -0.5V to $V_{CC}+0.5V$
- Input clamp current ----- -50mA
- Output clamp current ----- -50mA
- Continuous output current ----- $\pm 50mA$
- Storage Temperature ----- $-65^{\circ}C$ to $150^{\circ}C$

Recommended Operating Conditions

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Supply voltage	V_{CC}	Operating	1.65		5.5	V
Input voltage	V_I		0		5.5	V
Output voltage	V_O				V_{CC}	V
High- level input voltage	V_{IH}	$V_{CC} = 1.65V$ to $1.95V$	$0.65 \times V_{CC}$			V
		$V_{CC} = 2.3V$ to $2.7V$	1.7			
		$V_{CC} = 3V$ to $3.6V$	2			
		$V_{CC} = 4.5V$ to $5.5V$	$0.7 \times V_{CC}$			
Low- level input voltage	V_{IL}	$V_{CC} = 1.65V$ to $1.95V$			$0.35 \times V_{CC}$	V
		$V_{CC} = 2.3V$ to $2.7V$			0.7	
		$V_{CC} = 3V$ to $3.6V$			0.8	
		$V_{CC} = 4.5V$ to $5.5V$			$0.3 \times V_{CC}$	
High- level output current	I_{OH}	$V_{CC} = 1.65V$			-4	mA
		$V_{CC} = 2.3V$			-8	
		$V_{CC} = 3V$			-16	
		$V_{CC} = 3V$			-24	
		$V_{CC} = 4.5V$			-32	
Low- level output current	I_{OL}	$V_{CC} = 1.65V$			4	mA
		$V_{CC} = 2.3V$			8	
		$V_{CC} = 3V$			16	
		$V_{CC} = 3V$			24	
		$V_{CC} = 4.5V$			32	
Input transition rise or fall rate	$\Delta T/\Delta V$	$V_{CC} = 1.8V \pm 0.15V, 2.5V \pm 0.2V$			20	ns/V
		$V_{CC} = 3.3V \pm 0.3V$			10	
		$V_{CC} = 5V \pm 0.5V$			5	
Operating temperature	T_A		-40		125	$^{\circ}C$

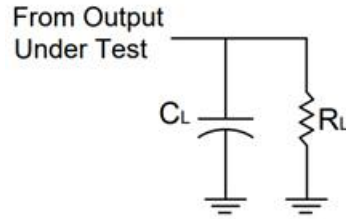
Electrical Characteristics

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
High- level output voltage	V_{OH}	$V_{CC} = 1.65\sim 5.5V, I_{OH} = -100\mu A$	$V_{CC}-0.1$			V
		$V_{CC} = 1.65V, I_{OH} = -4mA$	1.2			
		$V_{CC} = 2.3V, I_{OH} = -8mA$	1.9			
		$V_{CC} = 3V, I_{OH} = -16mA$	2.4			
		$V_{CC} = 3V, I_{OH} = -24mA$	2.3			
		$V_{CC} = 4.5V, I_{OH} = -32mA$	3.8			
Low- level output voltage	V_{OL}	$V_{CC} = 1.65\sim 5.5V, I_{OL} = 100\mu A$			0.1	V
		$V_{CC} = 1.65V, I_{OL} = 4mA$			0.45	
		$V_{CC} = 2.3V, I_{OL} = 8mA$			0.3	
		$V_{CC} = 3V, I_{OL} = 16mA$			0.4	
		$V_{CC} = 3V, I_{OL} = 24mA$			0.55	
		$V_{CC} = 4.5V, I_{OL} = 32mA$			0.55	
Input leakage current	I_I	$V_{IN} = 5.5V$ or GND, $V_{CC} = 0\sim 5.5V$			± 5	μA
Power off leakage current	I_{OFF}	V_{IN} or $V_O = 5.5V, V_{CC} = 0V$			± 10	μA
Supply current	I_{CC}	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0, V_{CC} = 1.65\sim 5.5V$			10	μA
Additional supply current per input pin	ΔI_{CC}	$V_{CC} = 3\sim 5.5V$, one input at $V_{CC} - 0.6V$, other input at V_{CC} or GND			500	μA

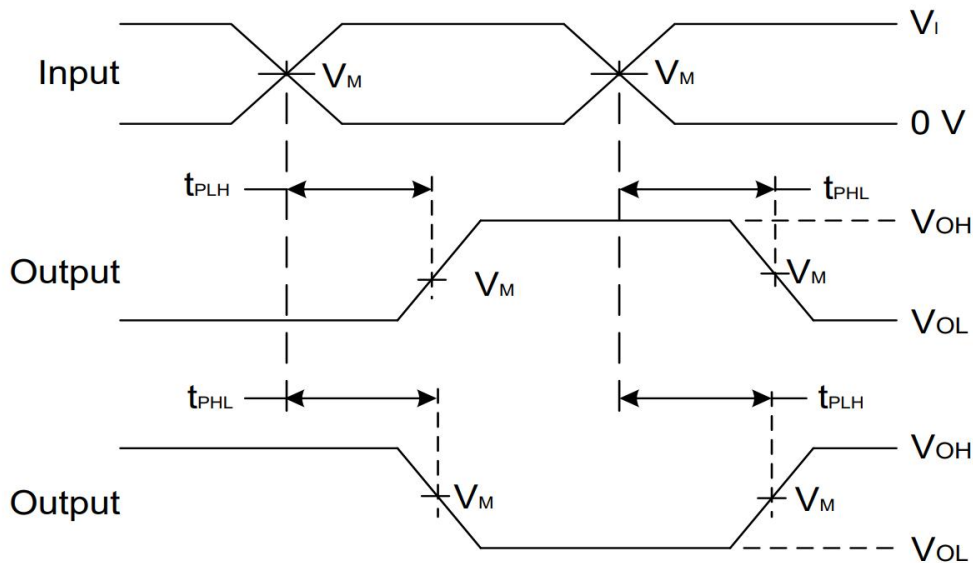
Switching Characteristics

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit		
Propagation delay from input(A) to output(Y)	T_{PD}	$V_{CC} = 1.8V \pm 0.15V$	$C_L = 15pF$ $R_L = 1M\Omega$			ns		
		$V_{CC} = 2.5V \pm 0.2V$					3.1	8
		$V_{CC} = 3.3V \pm 0.3V$					1.5	4.4
		$V_{CC} = 5V \pm 0.5V$					1.2	4.1
			1		3.2			

Parameter Measurement Information



V _{CC}	INPUTS		V _M	C _L	R _L
	V _I	t _r /t _f			
1.8V ± 0.15V	V _{CC}	≅ 2ns	V _{CC} /2	15pF	1MΩ
2.5V ± 0.2V	V _{CC}	≅ 2ns	V _{CC} /2	15pF	1MΩ
3.3V ± 0.3V	3V	≅ 2.5ns	1.5V	15pF	1MΩ
5V ± 0.5V	V _{CC}	≅ 2.5ns	V _{CC} /2	15pF	1MΩ



Voltage Waveform Propagation Delay Times
Inverting and Non Inverting Outputs

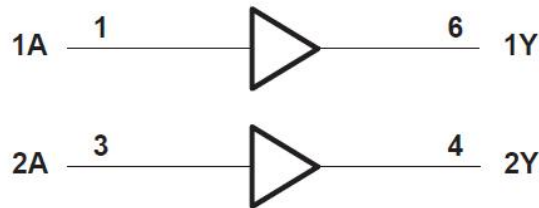
- Notes: A. C_L includes probe and jig capacitance
- B. All pulses and supplied at pulse repetition rate ≅ 10MHz
- C. t_{PLH} and t_{PHL} are the same as t_{PD}

IC Operation Information

Basic Operation

The FLG74LVC2G34 is a dual buffer gate that operates from 1.65-V to 5.5-V V_{CC} . Each buffer has a balanced output capable of outputting 32 mA at $V_{CC} = 4.5\text{ V}$. The overvoltage tolerant inputs allow for down translation of up to 6.5 V, and the partial power-off feature ensures that the inputs and outputs can be any value from -0.5 V to 6.5 V when V_{CC} is 0 V

Function Block Diagram



Feature Description

Nano Free package technology is a major breakthrough in IC packaging concepts, using the die as the package. This device supports 5-V V_{CC} operation and up to 5.5-V inputs. It has a low propagation delay of only 4.1 ns at 3.3 V. Power consumption is low with only 10- μA Max I_{CC} . Balanced drive output at 3.3 V can put out $\pm 24\text{-mA}$. Typical output ground bounce is less than 0.8 V at 3.3-V V_{CC} and typical output undershoot is greater than 2 V at $(3.3-V V_{CC})$. This device supports partial-power-down mode operation.

Device Functional Table

INPUTS	OUTPUT
A	Y
L	Hi-Z
H	L

IC Application Information

The FLG74LVC2G34 is a high-drive CMOS device that can be used as a buffer with a high output drive, such as an LED application. It can produce 24 mA of drive current at 3.3 V, making it ideal for driving multiple outputs and good for high-speed applications up to 100 MHz. The inputs are 5.5-V tolerant, allowing it to translate down to V_{CC}

Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because

it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

Detailed Design Procedure

1. Recommended Input Conditions

- Rise time and fall time specs. See ($\Delta t / \Delta V$) in the Recommended Operating Conditions table.
- Specified high and low levels. See (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
- Inputs are overvoltage tolerant allowing them to go as high as ($V_I \text{ max}$) in the Recommended Operating Conditions table at any valid V_{CC} .

2. Recommend Output Conditions

- Load currents should not exceed ($I_O \text{ max}$) per output and should not exceed total current (continuous current through V_{CC} or GND) for the part. These limits are located in the Absolute Maximum Ratings table
- Outputs should not be pulled above V_{CC} .

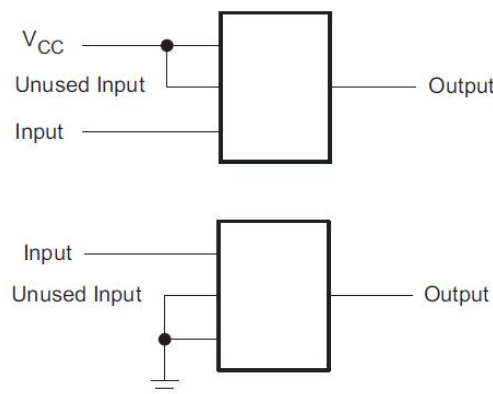
Power Supply Recommendations

The power supply can be any voltage between the min and max supply voltage rating located in the Recommended Operating Conditions table.

Each V_{CC} pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1- μF capacitor is recommended and if there are multiple V_{CC} pins then 0.01- μF or 0.022- μF capacitor is recommended for each power pin. It is ok to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1- μF and 1- μF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

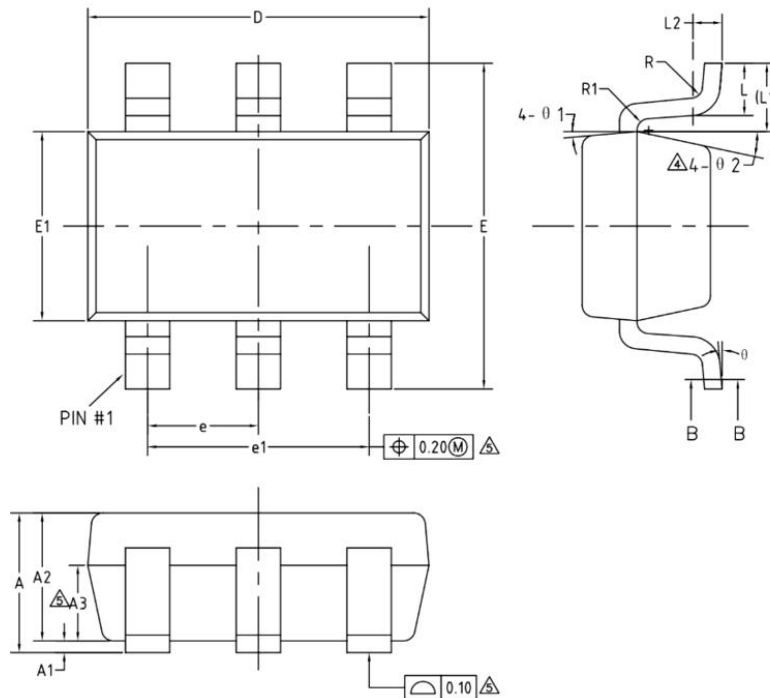
Layout Considerations

When using multiple bit logic devices inputs should not ever float. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input buffer gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} whichever make more sense or is more convenient.



Package Information

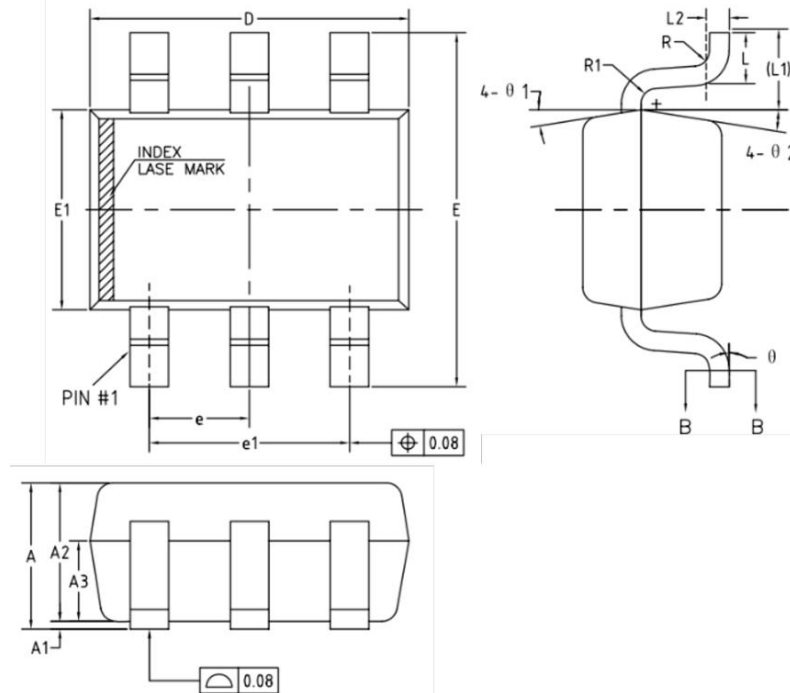
(1) Package Type:SOT23-6



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	—	—	1.25
A1	0	—	0.15
A2	1.00	1.10	1.20
A3	0.60	0.65	0.70
b	0.36	—	0.50
b1	0.36	0.38	0.45
c	0.14	—	0.20
c1	0.14	0.15	0.16
D	2.826	2.926	3.026
E	2.60	2.80	3.00
E1	1.526	1.626	1.726
e	0.90	0.95	1.00
e1	1.80	1.90	2.00
L	0.35	0.45	0.60
L1	0.59REF		
L2	0.25BSC		
R	0.10	—	—
R1	0.10	—	0.20
θ	0°	—	8°
$\theta 1$	3°	5°	7°
$\theta 2$	6°	—	14°

(2) Package Type: SC70-6



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	0.85	—	1.05
A1	0	—	0.10
A2	0.80	0.90	1.00
A3	0.47	0.52	0.57
b	0.22	—	0.29
b1	0.22	0.25	0.28
c	0.115	—	0.15
c1	0.115	0.13	0.14
D	2.02	2.07	2.12
E	2.20	2.30	2.40
E1	1.25	1.30	1.35
e	0.65BSC		
e1	1.30BSC		
L	0.28	0.33	0.38
L1	0.50REF		
L2	0.15BSC		
R	0.10	—	—
R1	0.10	—	0.25
θ	0°	—	8°
θ 1	6°	9°	12°
θ 2	6°	9°	12°

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